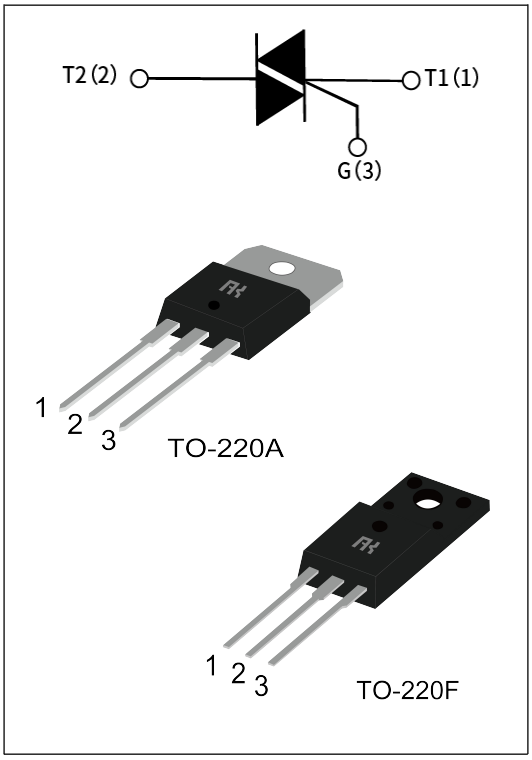
BTA24 Serial Standard TRIACS

GENERAL DESCRIPTION:

High current density due to double mesa technology; Glass Passivation.BTA24 series TRIACS is suitable for general purpose AC switching.they can be used as an ON/ OFF Function in applications such as static relays,heating regulation,induction motor stating circuits..or for phase control operation light dimmers,motor speed controllers.



Main Features:

$I_{T(RMS)}$	V_{DRM}/V_{RRM}	V_{TM}
25A	600V 800V 1200 V	≤1.5 V

Absolute Ratings(limiting values) :

Symbol	Parameter		Value	Unit
T_{stg}	Storage junction temperature range		- 40 to + 150	℃
T_j	Operating junction temperature range		- 40 to + 125	℃
$I_{T(RMS)}$	RMS on-state current	TO-220F(Ins) (TC=75℃)	25	A
		TO-220A(Ins) (TC=70℃)		
I_{TSM}	Non repetitive surge peak on-state current (full cycle, F=50Hz)		250	A
V_{DRM}	Repetitive peak off-state voltage(Tj =25℃)		600/800/1200	V
V_{RRM}	Repetitive peak reverse voltage(Tj =25℃)		600/800/1200	V
V_{DSM}	Non repetitive surge peak Off-state voltage		V_{DRM} + 100	V
V_{RSM}	Non repetitive peak reverse voltage		V_{RRM} + 100	V
I^2t	I^2t value for fusing tp = 10 ms		340	A^2s
dI/dt	Critical rate of rise of on-state current (I_G =2×I_{GT})		50	A/μs

I_{GM}	Peak gate current	4	A
$P_{G(AV)}$	Average gate power dissipation	1	W
P_{GM}	Peak gate power	10	W

Electrical Characteristics : (Tj=25℃ unless otherwise specified)

Symbol	Test Condition	Quadrant	Range	V_{DRM} /V_{RRM}: 600/800V		V_{DRM} /V_{RRM}: 1200		Unit
				B	C	B	C	
I_{GT}	V_D=12V R_L=33Ω	I-II-III	MAX	50	35	50	35	mA
V_{GT}		I-II-III	MAX	1.3		1.5		V
V_{GD}	V_D=V_{DRM} R_L=3.3kΩ T_j=125°C	I-II-III	MIN	0.2				V
I_L	I_G=1.2 I_{GT}	I-III	MAX	80	70	90	70	mA
		II		100	80	100	80	
I_H	I_{TM}= 100mA		MAX	75	50	80	60	mA
dV/dt	V_D=2/3V_{DRM} Gate Open T_j=125°C		MIN	1000	500	1500	1000	V/μs
(dV/dt)c	(dI/dt)c=8.8A/ms Tj=125℃		MIN	22	13	30	20	V/μs

Static Characteristics

Symbol	Parameter		Value(MAX)	Unit
V_{TM}	I_{TM}=35A tp= 380μs	T_j=25°C	1.5	V
I_{DRM} I_{RRM}	V_D=V_{DRM} ,V_R=V_{RRM}	T_j=25°C	5	μA mA
		T_j=125°C	3	

Thermal Resistances :

Symbol	Parameter		Value	Unit
Rth(j-c)	Junction to case for AC	TO-220A(Ins)	1.75	°C/W
		TO-220F(Ins)	1.7	

Fig.1: Maximum power dissipation versus RMS on-state current

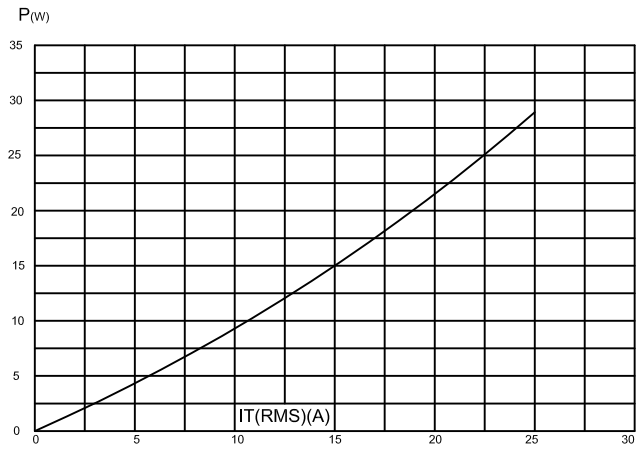


Fig.2 : RMS on-state current versus case temperature

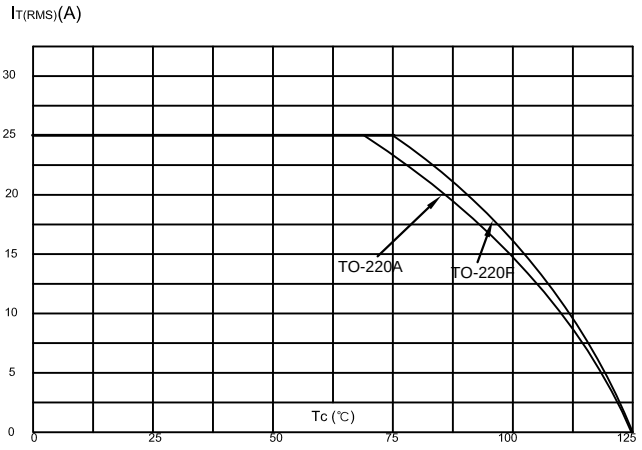


Fig.3 : Surge peak on-state current versus number of cycles

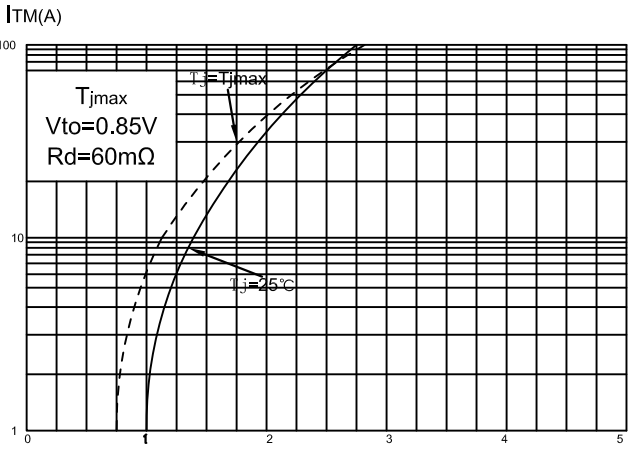


Fig.4 : On-state characteristics (maximum values)

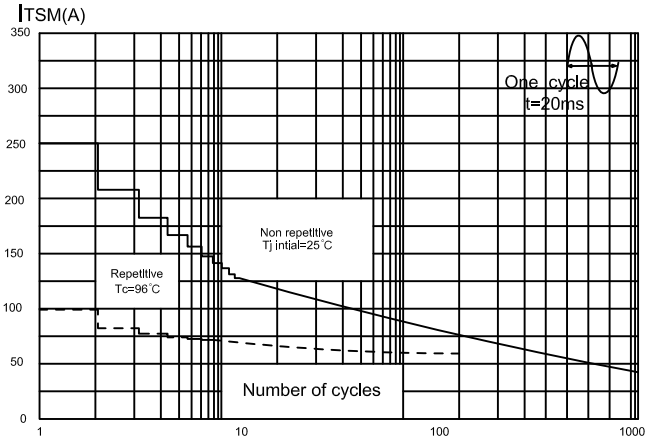


Fig.5 : Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<10ms and corresponding value of I t (dI/dt <50A/μs)

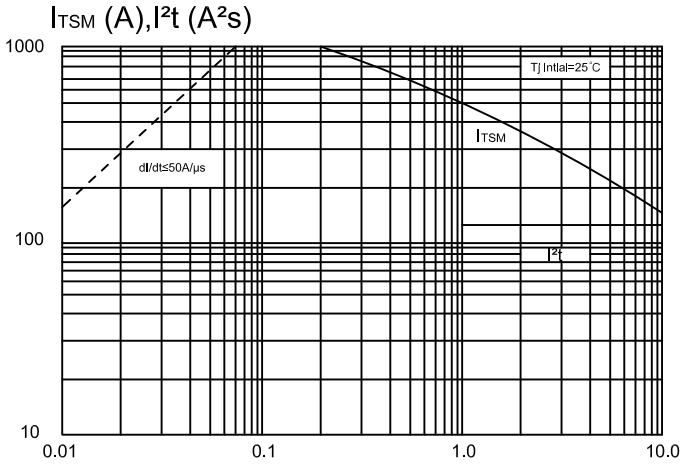
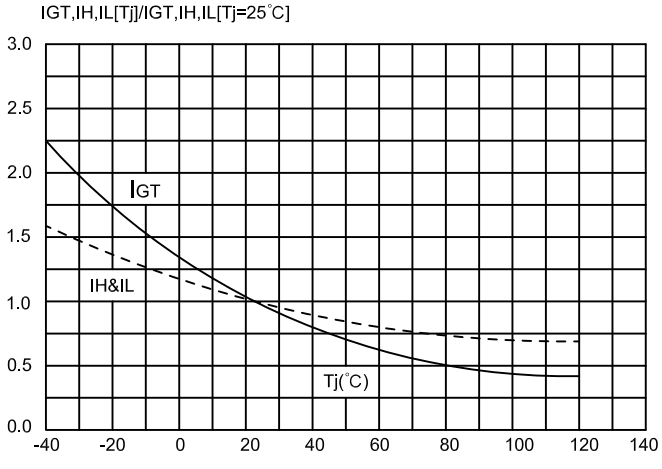
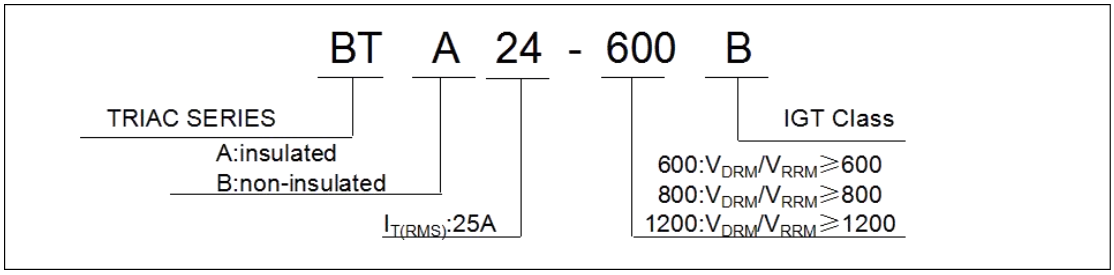


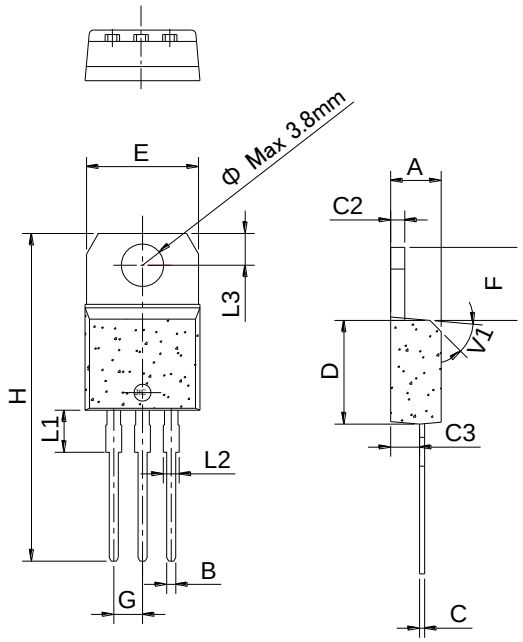
Fig.6: Relative variations of gate trigger current,holding current and latching current versus unction temperature



Ordering Information:

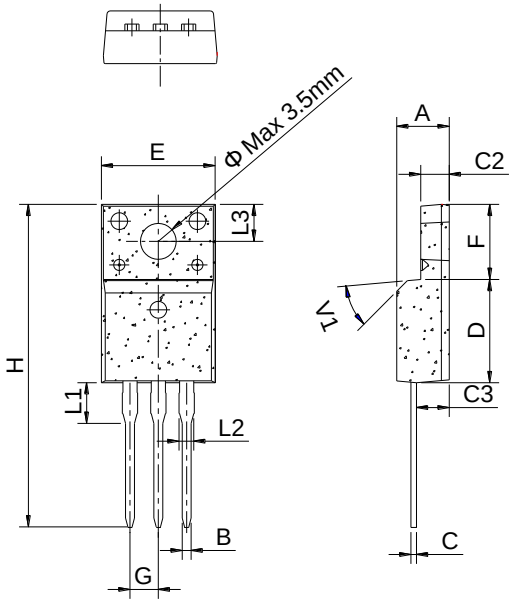


Package Mechanical Data :



TO-220A Ins

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.60		10.4	0.378		0.409
F	6.20		6.60	0.244		0.260
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	



TO-220F Ins

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.80	0.173		0.189
B	0.74	0.80	0.83	0.029	0.031	0.033
C	0.48		0.75	0.019		0.030
C2	2.40		2.70	0.094		0.106
C3	2.60		3.00	0.102		0.118
D	8.80		9.30	0.346		0.366
E	9.70		10.3	0.382		0.406
F	6.40		7.00	0.252		0.276
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.63			0.143	
L2	1.14		1.70	0.045		0.067
L3		3.30			0.130	
V1		45°			45°	